

# BGM704N7

FM Radio LNA with Integrated RX/TX Switch

## Data Sheet

Revision 2.1, 2010-10-19  
Preliminary

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**BGM704N7 FM Radio LNA with Integrated RX/TX Switch**

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Page	Subjects (major changes since last revision)
12-23	Updated performance values

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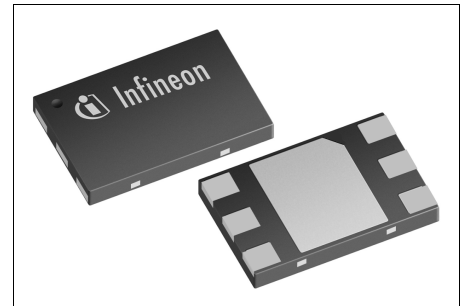
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## 1 Features

Main features:

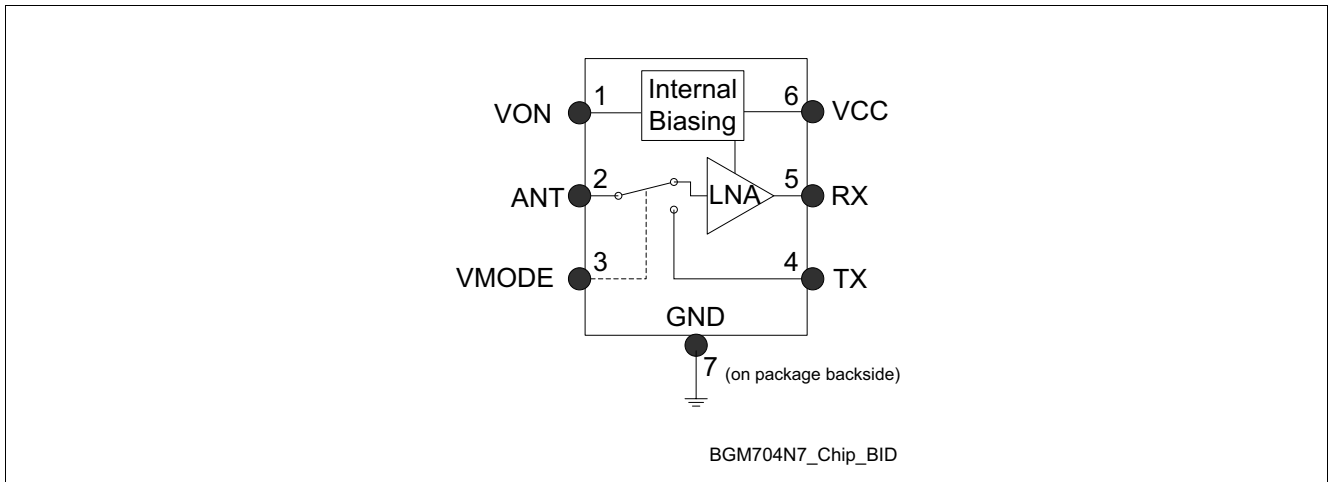
- High performance FM radio LNA with integrated biasing and RX/TX switch
- Worldwide FM band support (76-108 MHz)
- Designed for high ohmic antenna
- 2kV HBM ESD protection
- Very high gain at low current consumption
- High input compression point
- Integrated active biasing circuit enables stable operation point against temperature and process-variation
- Operation voltage: 1.8 V to 3.6 V
- Standby mode
- Very small and leadless package TSNP-7-1, 2.0 x 1.3 x 0.4 mm
- Pb-free (RoHS compliant) and halogen-free (WEEE compliant) package



### Description

The BGM704N7 is a high performance Silicon Germanium Carbon (SiGe:C) FM radio LNA with integrated RX/TX switch and active biasing in a very small TSNP-7-1 package for use in FM radio systems.

Product Name	Package	Chip	Marking
BGM704N7	TSNP-7-1	T1585	tbd



**Figure 1** Block Diagram of FM Radio Module



## 2 Electrical Characteristics

### 2.1 Absolute Maximum Ratings

**Table 1 Absolute Maximum Ratings**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply voltage	$V_{CC}$	-0.3	–	3.6	V	–
Supply current	$I_{CC}$	–	–	25	mA	–
Control voltage	$V_{MODE}$	-0.3	–	$V_{CC} + 0.3$	V	–
On / Off voltage	$V_{ON}$	-0.3	–	$V_{CC} + 0.3$	V	–
Pin voltage ANT Pin	$V_{RFIN}$	-0.3	–	0.9	V	–
RF input power	$P_{RFIN}$	–	–	tbd	dBm	–
Junction temperature	$T_j$	–	–	150	°C	–
Ambient temperature range	$T_A$	-30	–	85	°C	–
Storage temperature range	$T_{stg}$	-65	–	150	°C	–

**Attention:** Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the integrated circuit.

### 2.2 Thermal Resistance

**Table 2 Thermal Resistance**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Thermal resistance junction to soldering point	$R_{thJS}$	–	–	tbd	K/W	–

### 2.3 ESD Integrity

**Table 3 ESD Integrity**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
ESD hardness HBM <sup>1)</sup>	$V_{ESD-HBM}$	–	2000	–	V	All pins

1) According to JESD22-A114

## 2.4 DC Characteristics

**Table 4** DC Characteristics,  $T_A = 25\text{ °C}$

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Supply voltage	$V_{CC}$	1.8	3.0	3.6	V	–
Supply current RX mode	$I_{CC}$	–	3.6	–	mA	–
Supply current TX mode	$I_{CC}$	–	0.4	–	mA	–
Supply current standby mode	$I_{CCOFF}$	–	0.1	2	$\mu\text{A}$	–
Logic level high	$V_{HI}$	1.5	3.0	–	V	All logic pins
Logic level low	$V_{LO}$	–	0.0	0.5	V	
Logic currents	$I_{LO}$	–	0.1	–	$\mu\text{A}$	All logic pins
	$I_{HI}$	–	5.0	–	$\mu\text{A}$	

## 2.5 RX/TX Control Truth Table

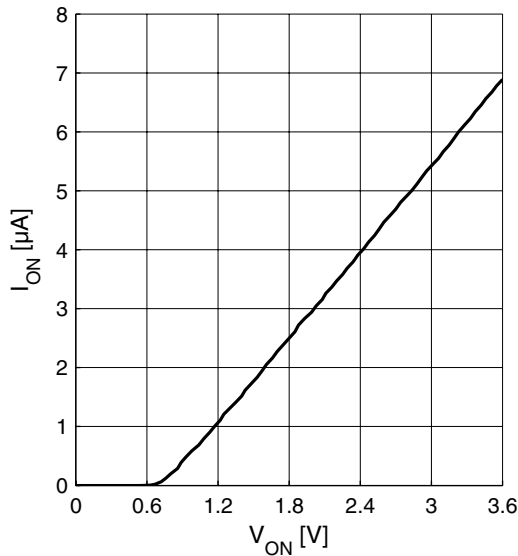
**Table 5** Band Select Truth Table

	RX Mode	TX Mode	Standby
VON	H	H	L
VMODE	H	L	x

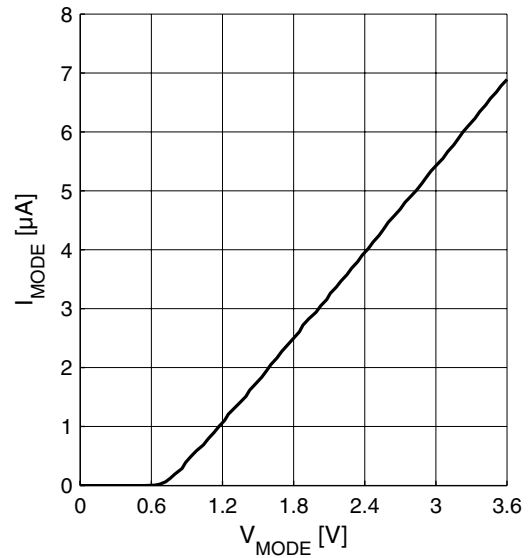
## 2.6 Logic Signal Characteristics

Current consumption of logic inputs VON, VMODE

**Logic currents**  $I_{ON} = f(V_{ON})$   
 $V_{CC} = 3.0 \text{ V}$ ,  $T_A = 25 \text{ }^\circ\text{C}$



**Logic currents**  $I_{MODE} = f(V_{MODE})$   
 $V_{CC} = 3.0 \text{ V}$ ,  $T_A = 25 \text{ }^\circ\text{C}$



## 2.7 Switching Times

**Table 6** Typical Switching Times;  $T_A = -30 \dots 85 \text{ }^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Control settling time	$t_{MODE}$	–	3	–	μs	Switching RX ↔ TX (pin VMODE)
Power on settling time	$t_{ON}$	–	5	–	μs	Switching from standby mode to ON mode (pin VON)

## 2.8 Measured RF Characteristics RX Mode in 50 Ω System, $V_{CC} = 1.8\text{ V}$

**Table 7** Typical Characteristics 100 MHz,  $T_A = 25\text{ °C}$ ,  $V_{CC} = 1.8\text{ V}$ ,  $V_{ON} = 1.8\text{ V}$ ,  $V_{MODE} = 1.8\text{ V}^1)$

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pass band range		76	–	108	MHz	–
Current consumption	$I_{CC}$	–	3.3	–	mA	–
Gain	$S_{21}$	–	12.0	–	dB	–
Reverse Isolation <sup>2)</sup>	$S_{12}$	–	-54	–	dB	–
Noise figure	$NF$	–	3.5	–	dB	–
Input return loss <sup>2)</sup>	$S_{11}$	–	-0.6	–	dB	50 Ω
Output return loss <sup>2)</sup>	$S_{22}$	–	-14	–	dB	50 Ω
Stability factor <sup>3)</sup>	$k$	–	>2.9	–	–	DC to 8 GHz
Input compression point <sup>2)</sup>	$IP_{1dB}$	–	-9	–	dBm	–
Inband IIP3 <sup>2)</sup> $f_1 - f_2 = 1\text{ MHz}$	$IIP3$	–	-13	–	dBm	–

1) Performance based on application circuit in Figure 2 on Page 24

2) Verification based on AQL; random production test

3) Guaranteed by device design; not tested in production

## 2.9 Measured RF Characteristics RX Mode in 50 Ω System, $V_{CC} = 3.0\text{ V}$

**Table 8** Typical Characteristics 100 MHz,  $T_A = 25\text{ °C}$ ,  $V_{CC} = 3.0\text{ V}$ ,  $V_{ON} = 3.0\text{ V}$ ,  $V_{MODE} = 3.0\text{ V}^1)$

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pass band range		76	–	108	MHz	–
Current consumption	$I_{CC}$	–	3.6	–	mA	–
Gain	$S_{21}$	–	12.5	–	dB	–
Reverse Isolation <sup>2)</sup>	$S_{12}$	–	-55	–	dB	–
Noise figure	$NF$	–	2.9	–	dB	–
Input return loss <sup>2)</sup>	$S_{11}$	–	-0.6	–	dB	50 Ω
Output return loss <sup>2)</sup>	$S_{22}$	–	-14	–	dB	50 Ω
Stability factor <sup>3)</sup>	$k$	–	>2.4	–	–	DC to 8 GHz
Input compression point <sup>2)</sup>	$IP_{1dB}$	–	-7	–	dBm	–
Inband IIP3 <sup>2)</sup> $f_1 - f_2 = 1\text{ MHz}$	$IIP3$	–	-14	–	dBm	–

1) Performance based on application circuit in Figure 2 on Page 24

2) Verification based on AQL; random production test

3) Guaranteed by device design; not tested in production

## 2.10 Measured RF Characteristics TX Mode in 50 Ω System, $V_{CC} = 1.8\text{ V}$

**Table 9** Typical Characteristics 100 MHz,  $T_A = 25\text{ °C}$ ,  $V_{CC} = 1.8\text{ V}$ ,  $V_{ON} = 1.8\text{ V}$ ,  $V_{MODE} = 0\text{ V}$ <sup>1)</sup>

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pass band range		76	–	108	MHz	–
Current consumption	$I_{CC}$	–	0.30	–	mA	–
Gain	$S_{21}$	–	-2.5	–	dB	–
Reverse Isolation <sup>2)</sup>	$S_{12}$	–	-2.5	–	dB	–
Input return loss <sup>2)</sup>	$S_{11}$	–	-12	–	dB	50 Ω
Output return loss <sup>2)</sup>	$S_{22}$	–	-12	–	dB	50 Ω
Stability factor <sup>3)</sup>	$k$	–	>1	–	–	DC to 8 GHz
Input compression point <sup>2)</sup>	$IP_{1dB}$	–	6	–	dBm	–
Inband IIP3 <sup>2)</sup> $f_1 - f_2 = 1\text{ MHz}$	$IIP3$	–	9	–	dBm	–

1) Performance based on application circuit in Figure 2 on Page 24

2) Verification based on AQL; random production test

3) Guaranteed by device design; not tested in production

## 2.11 Measured RF Characteristics TX Mode in 50 Ω System, $V_{CC} = 3.0\text{ V}$

**Table 10** Typical Characteristics 100 MHz,  $T_A = 25\text{ °C}$ ,  $V_{CC} = 3.0\text{ V}$ ,  $V_{ON} = 3.0\text{ V}$ ,  $V_{MODE} = 0\text{ V}$ <sup>1)</sup>

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pass band range		76	–	108	MHz	–
Current consumption	$I_{CC}$	–	0.40	–	mA	–
Gain	$S_{21}$	–	-1.6	–	dB	–
Reverse Isolation <sup>2)</sup>	$S_{12}$	–	-1.6	–	dB	–
Input return loss <sup>2)</sup>	$S_{11}$	–	-14	–	dB	50 Ω
Output return loss <sup>2)</sup>	$S_{22}$	–	-14	–	dB	50 Ω
Stability factor <sup>3)</sup>	$k$	–	>1	–	–	DC to 8 GHz
Input compression point <sup>2)</sup>	$IP_{1dB}$	–	10	–	dBm	–
Inband IIP3 <sup>2)</sup> $f_1 - f_2 = 1\text{ MHz}$	$IIP3$	–	15	–	dBm	–

1) Performance based on application circuit in Figure 2 on Page 24

2) Verification based on AQL; random production test

3) Guaranteed by device design; not tested in production

**2.12 Measured RF Characteristics RX Mode (ANT 5 kΩ -> RX 50 Ω),  $V_{CC} = 3.0 V$**

**Table 11 Typical Characteristics 100 MHz,  $T_A = 25\text{ °C}$ ,  $V_{CC} = 3.0 V$ ,  $V_{ON} = 3.0 V$ ,  $V_{MODE} = 3.0 V$ <sup>1)</sup>**

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Pass band range		76	–	108	MHz	–
Current consumption	$I_{CC}$	–	3.6	–	mA	–
Transducer gain <sup>2)</sup>	$S_{21}$	–	20.0	–	dB	$Z_S = 5\text{ k}\Omega$ $Z_L = 50\ \Omega$
Noise figure <sup>2)</sup>	$NF$	–	5.5	–	dB	$Z_S = 5\text{ k}\Omega$ $Z_L = 50\ \Omega$

1) Performance based on application circuit in Figure 3 on Page 25

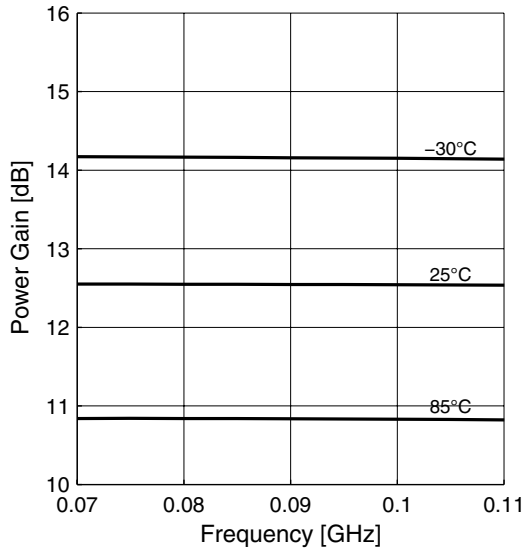
2) Guaranteed by device design; not tested in production



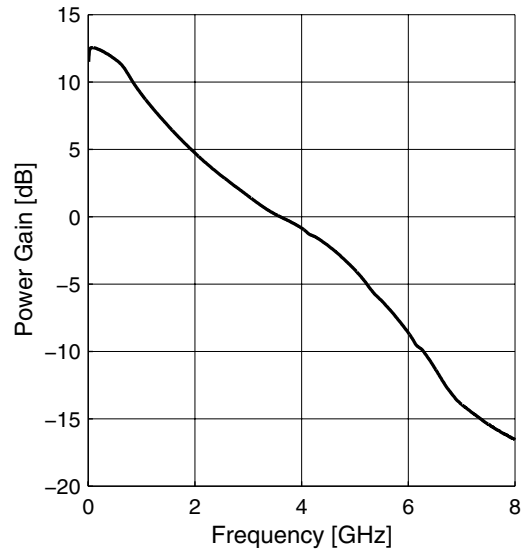
**2.13 Measured Performance RX Mode in 50 Ω System vs. Frequency**

$T_A = 25\text{ °C}$ ,  $V_{CC} = 3.0\text{ V}$ ,  $V_{ON} = 3.0\text{ V}$ ,  $V_{MODE} = 3.0\text{ V}$

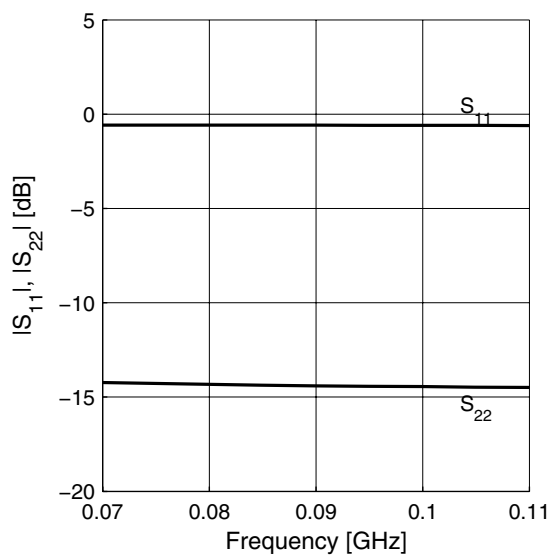
**Power Gain  $|S_{21}| = f(f)$**



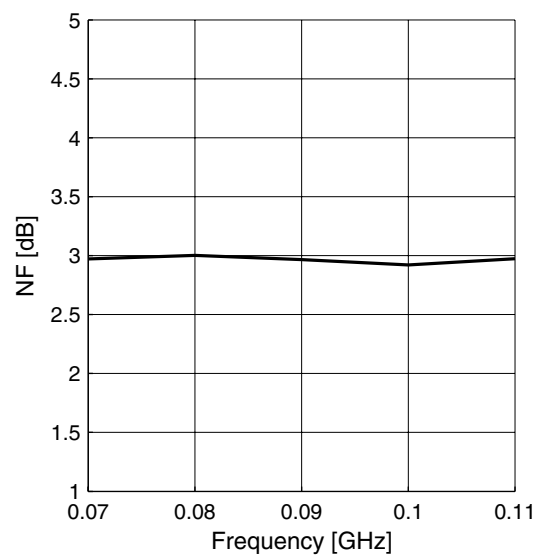
**Power Gain wideband  $|S_{21}| = f(f)$**



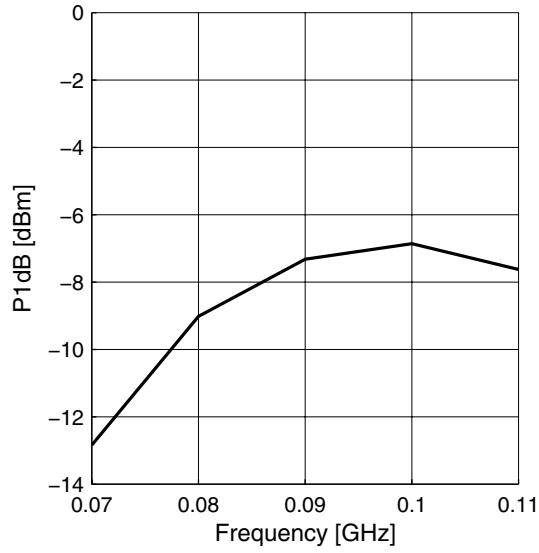
**Matching  $|S_{11}| = f(f)$ ,  $|S_{22}| = f(f)$**



**Noise Figure  $NF = f(f)$**



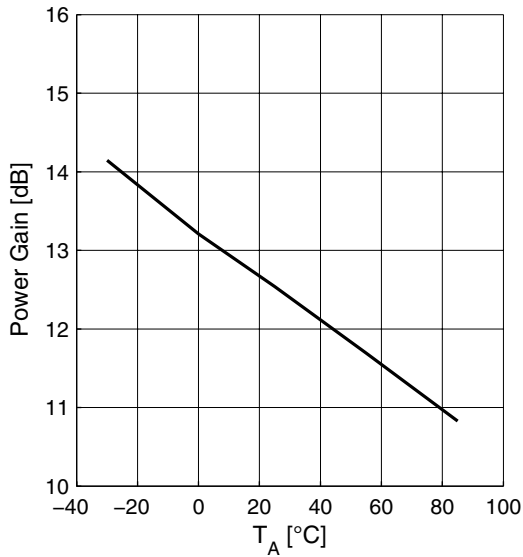
Input Compression  $P1dB = f(f)$



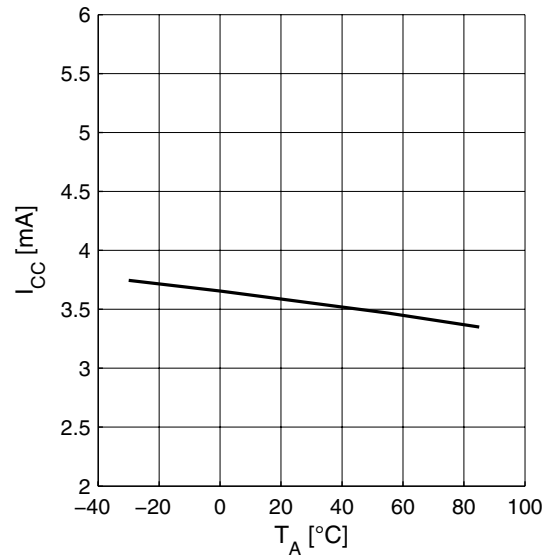
### 2.14 Measured Performance RX Mode in 50 Ω System vs. Temperature

$V_{CC} = 3.0\text{ V}$ ,  $V_{ON} = 3.0\text{ V}$ ,  $V_{MODE} = 3.0\text{ V}$ ,  $f = 100\text{ MHz}$

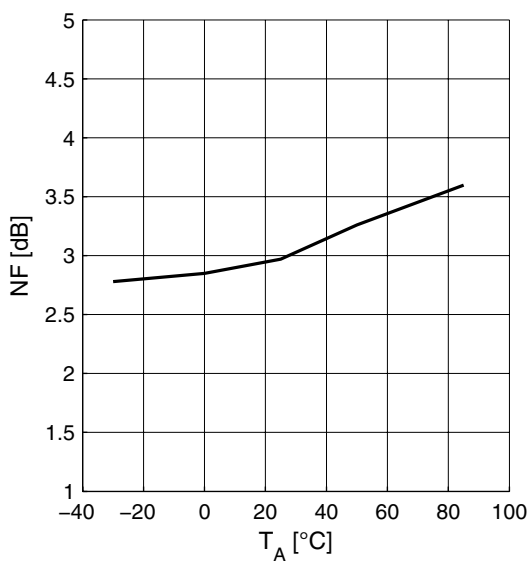
Power Gain  $|S_{21}| = f(T_A)$



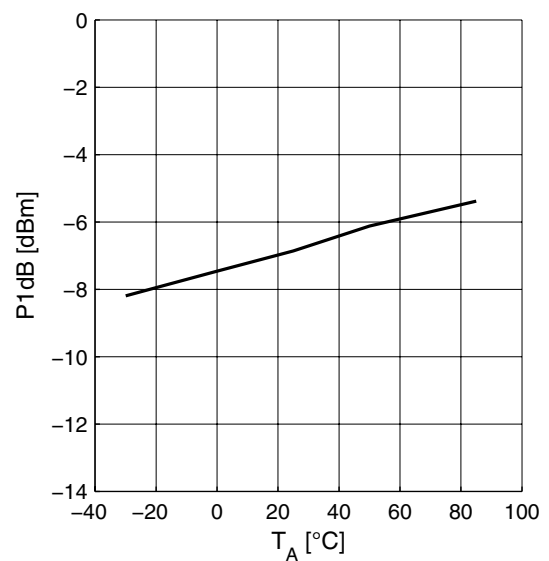
Supply Current  $I_{CC} = f(T_A)$



Noise Figure  $NF = f(T_A)$



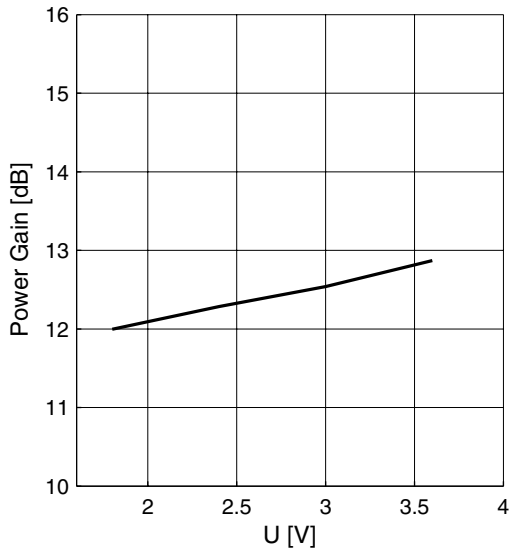
Input Compression  $P1dB = f(T_A)$



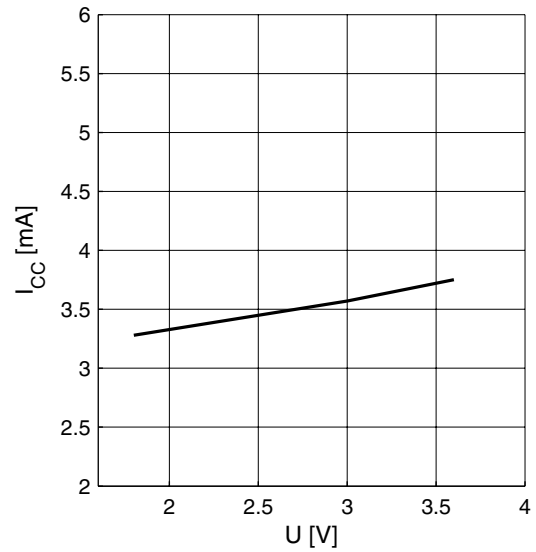
**2.15 Measured Performance RX Mode in 50 Ω System vs. Voltage**

$V_{CC} = 3.0\text{ V}$ ,  $V_{ON} = 3.0\text{ V}$ ,  $V_{MODE} = 3.0\text{ V}$ ,  $f = 100\text{ MHz}$

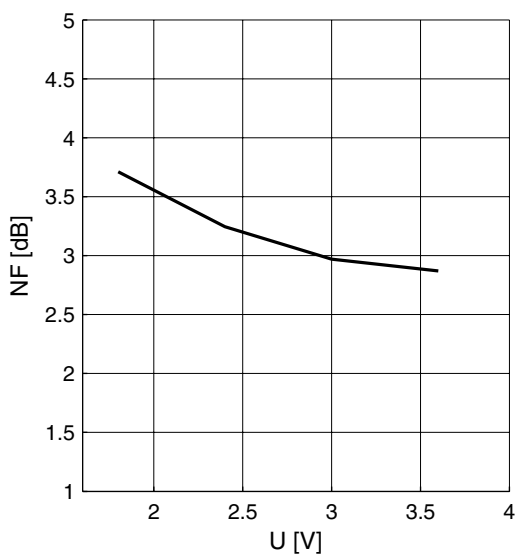
**Power Gain  $|S_{21}| = f(V)$**



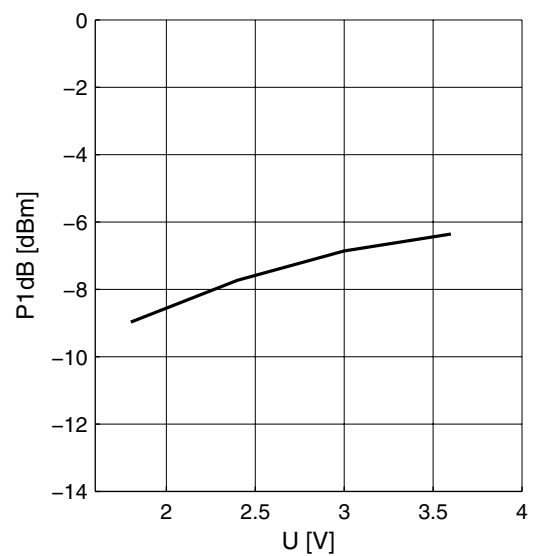
**Supply Current  $I_{CC} = f(V)$**



**Noise Figure  $NF = f(V)$**



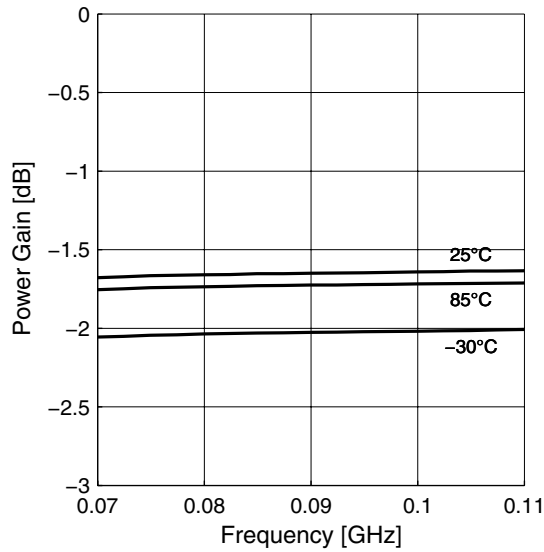
**Input Compression  $P1dB = f(V)$**



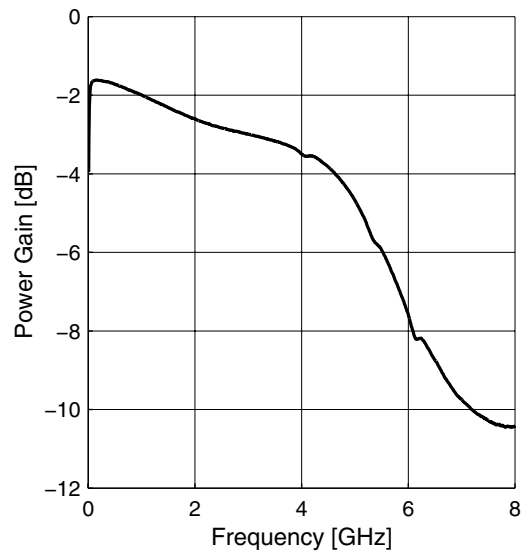
### 2.16 Measured Performance TX Mode in 50 Ω System vs. Frequency

$T_A = 25\text{ }^\circ\text{C}$ ,  $V_{CC} = 3.0\text{ V}$ ,  $V_{ON} = 3.0\text{ V}$ ,  $V_{MODE} = 0\text{ V}$

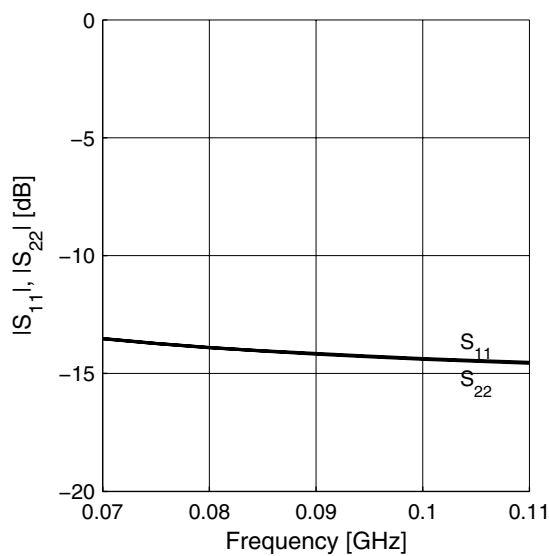
Power Gain  $|S_{21}| = f(f)$



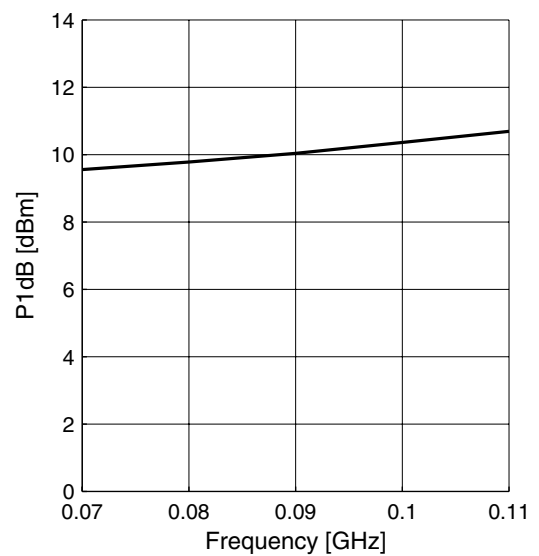
Power Gain wideband  $|S_{21}| = f(f)$



Matching  $|S_{11}| = f(f)$ ,  $|S_{22}| = f(f)$



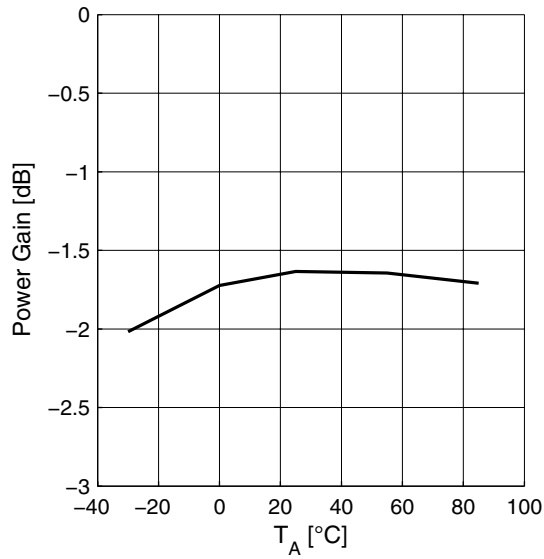
Input Compression  $P1dB = f(f)$



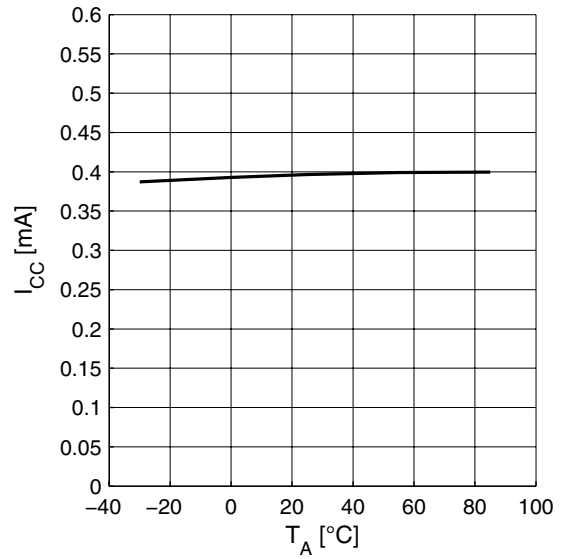
**2.17 Measured Performance TX Mode in 50 Ω System vs. Temperature**

$V_{CC} = 3\text{ V}$ ,  $V_{ON} = 3\text{ V}$ ,  $V_{MODE} = 0\text{ V}$ ,  $f = 100\text{ MHz}$

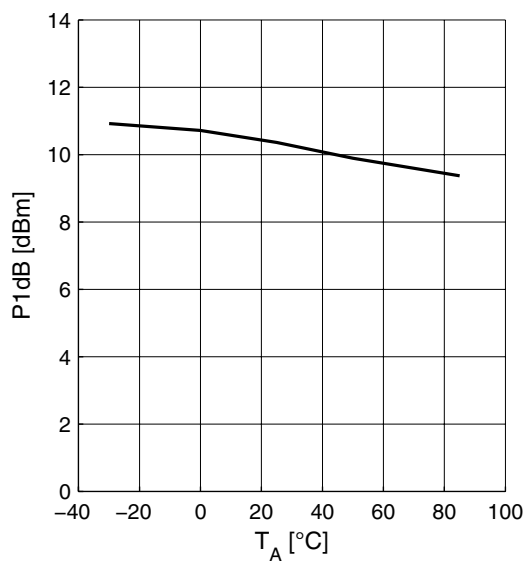
**Power Gain  $|S_{21}| = f(T_A)$**



**Supply Current  $I_{CC} = f(T_A)$**



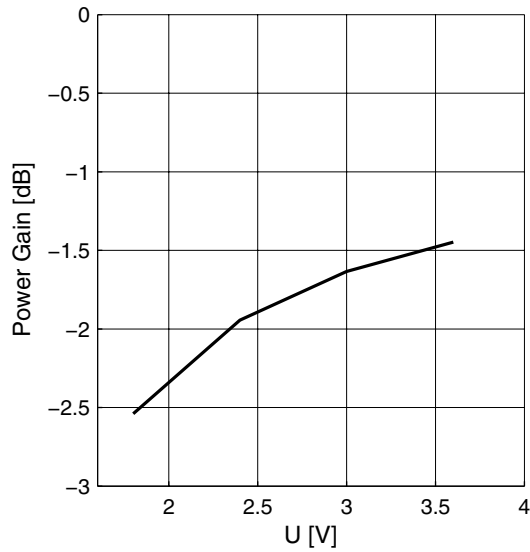
**Input Compression  $P1dB = f(T_A)$**



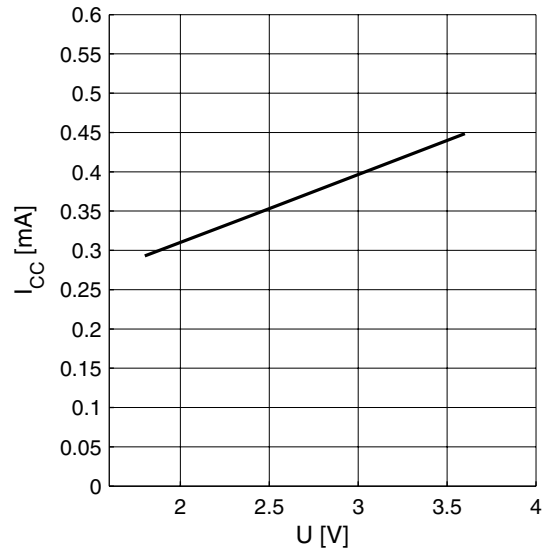
### 2.18 Measured Performance TX Mode in 50 Ω System vs. Voltage

$V_{CC} = 3\text{ V}$ ,  $V_{ON} = 3\text{ V}$ ,  $V_{MODE} = 0\text{ V}$ ,  $f = 100\text{ MHz}$

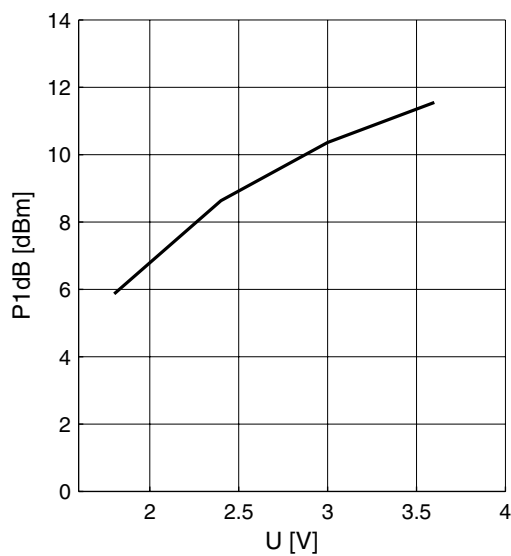
Power Gain  $|S_{21}| = f(V)$



Supply Current  $I_{CC} = f(V)$

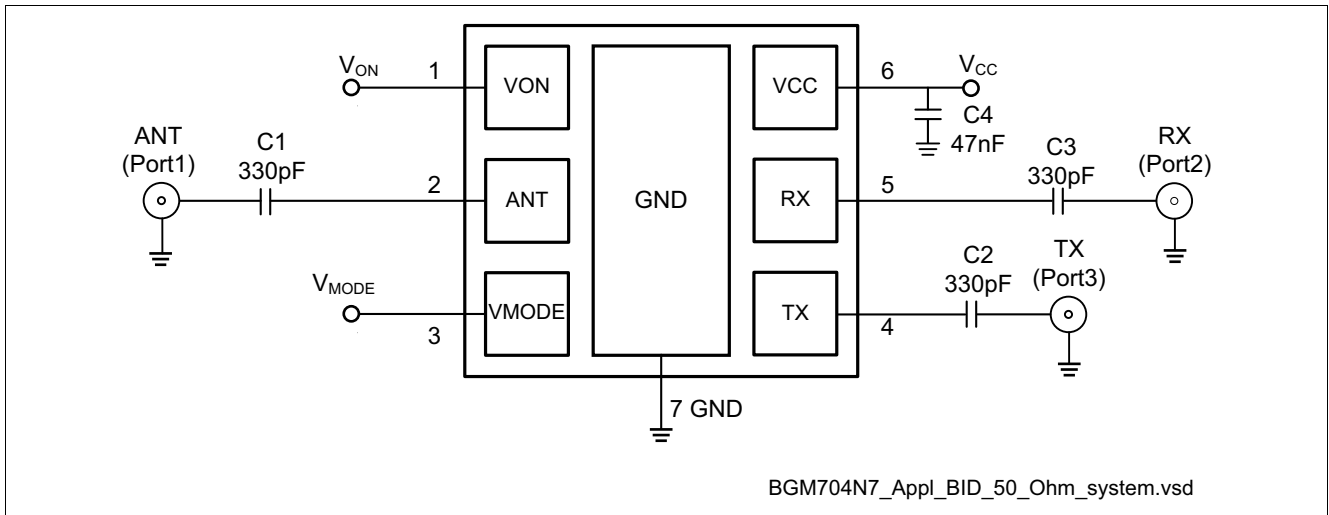


Input Compression  $P1dB = f(V)$



### 3 Application Circuit and Block Diagram

#### 3.1 FM Radio in 50 Ω System Application Circuit Schematic



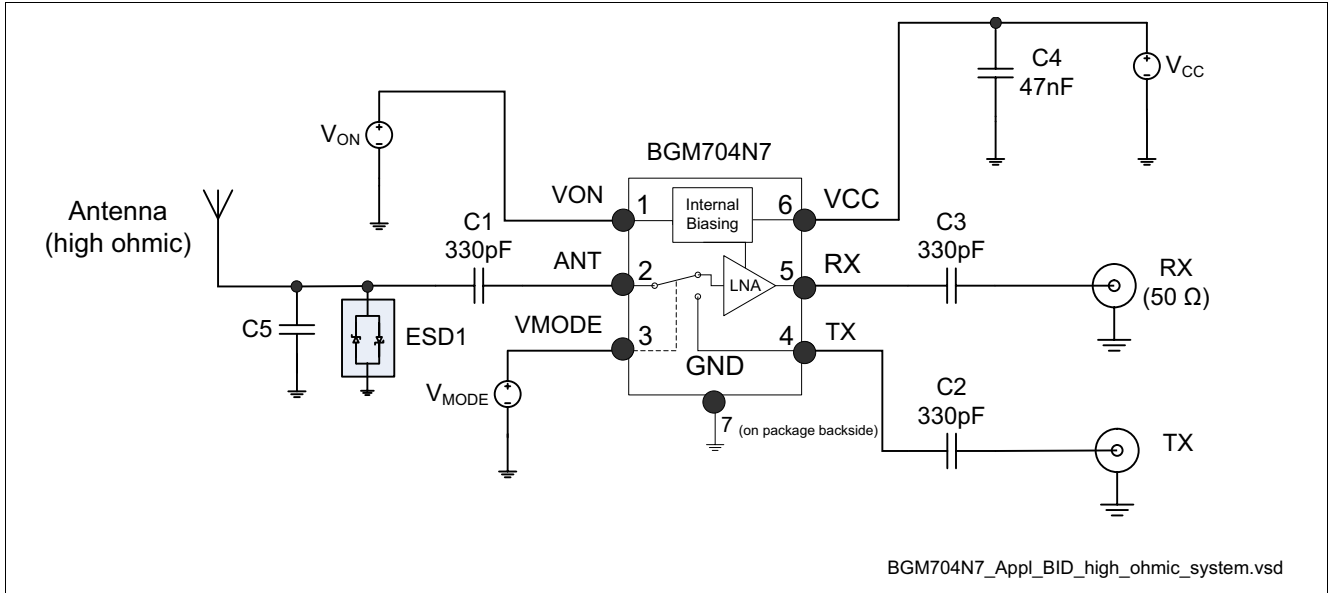
**Figure 2 Application Circuit with Chip Outline (Top View)**

**Table 12 Bill of Materials 50 Ω Application**

Part Number	Part Type	Manufacturer	Size	Comment
C1 ... C4	Chip capacitor	Various	0402	



### 3.2 FM Radio in High Ohmic System Application Circuit Schematic



**Figure 3 Application Circuit with Chip Outline High Ohmic (Top View)**

**Table 13 Bill of Materials High Ohmic Antenna Application**

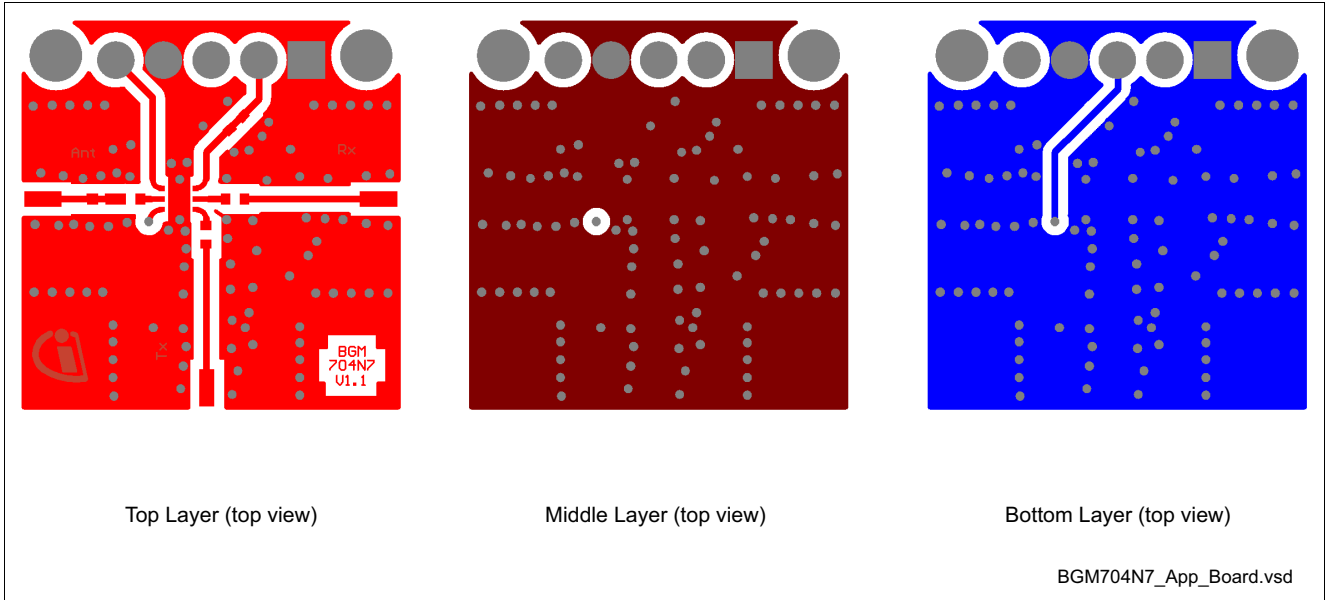
Part Number	Part Type	Manufacturer	Size	Comment
C1 ... C5	Chip capacitor	Various	0402	
ESD1	TVS diode ESD0P8RFL	Infineon	0402	Optional

### 3.3 Pin Description

**Table 14 Pin Definition and Function**

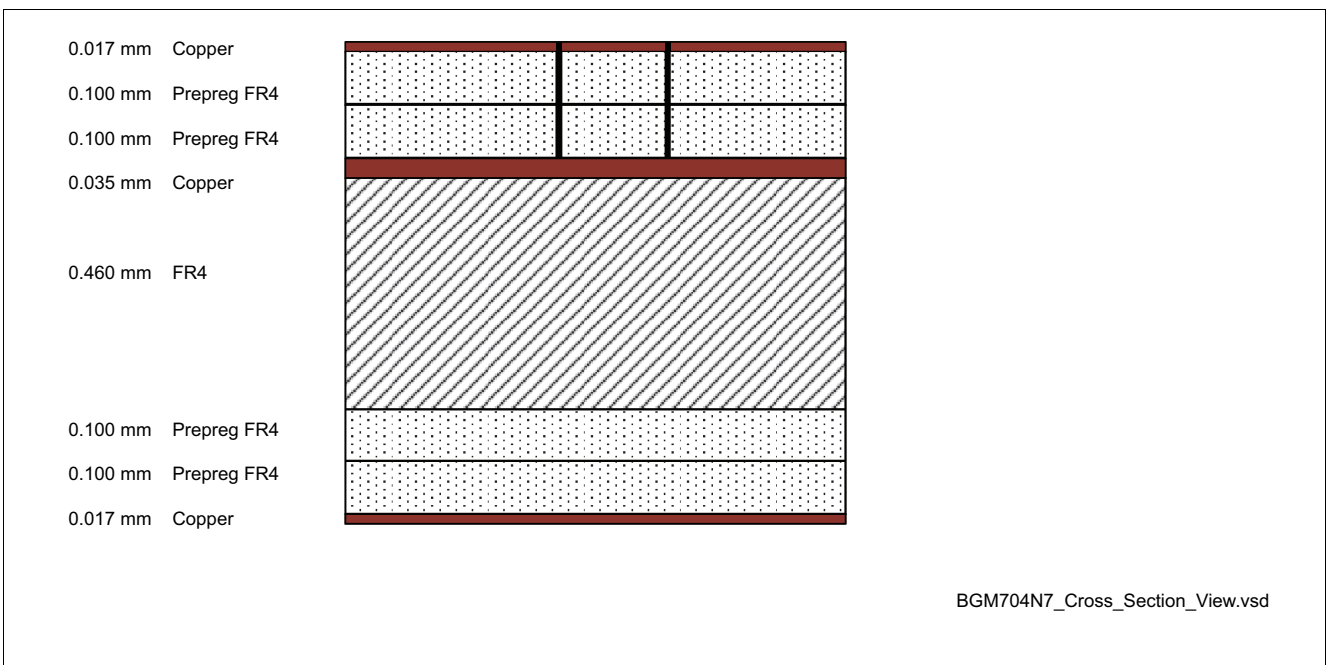
Pin No.	Name	Pin Type	Buffer Type	Function
1	VON	–	–	On / Off voltage
2	ANT	–	–	RF antenna (input / output)
3	VMODE	–	–	Control voltage
4	TX	–	–	RF input TX
5	RX	–	–	RF output RX
6	VCC	–	–	Supply voltage
7	GND	–	–	Ground connection for LNA and control circuitry (package paddle)

### 3.4 Application Board

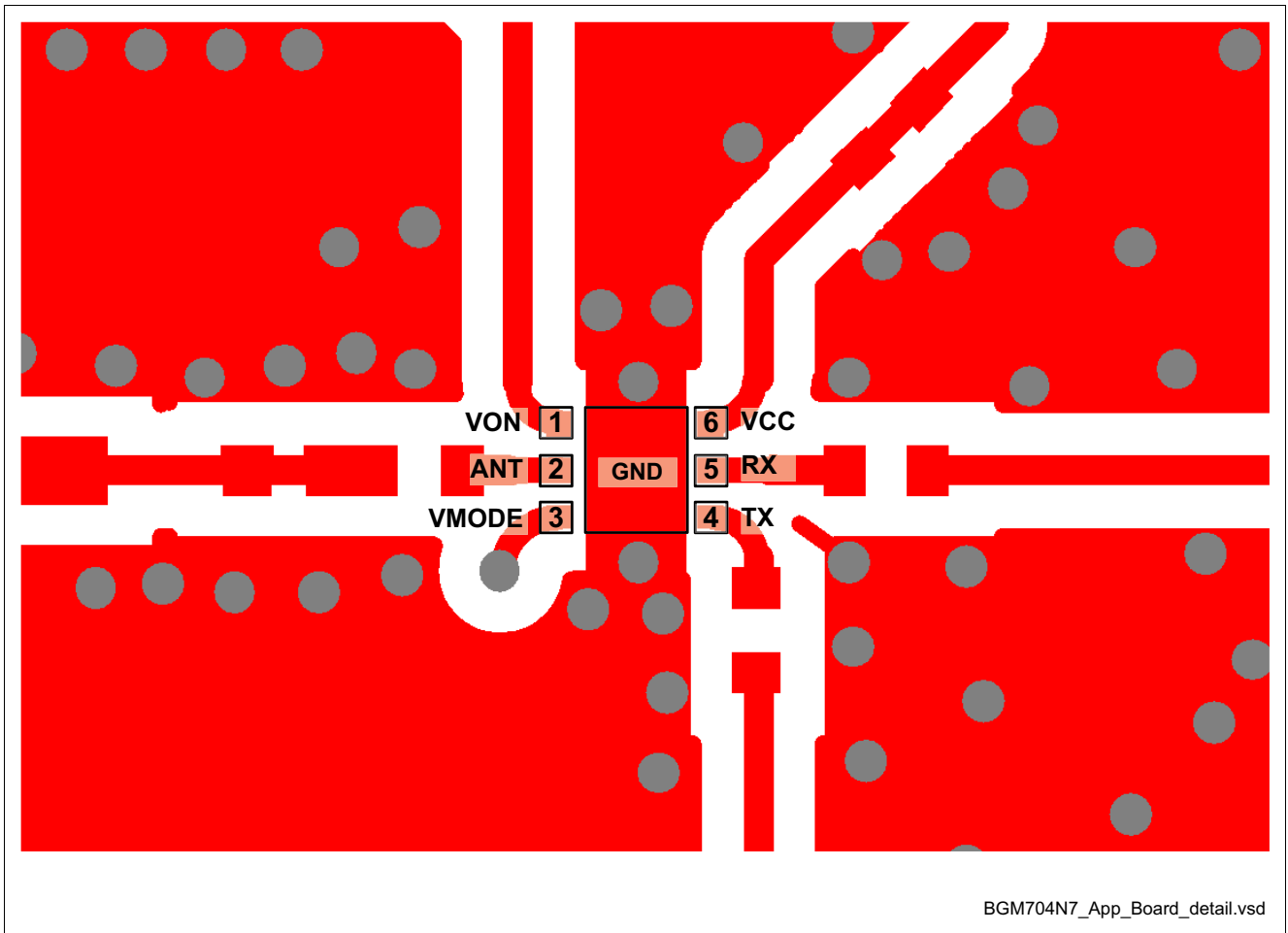


**Figure 4 Application Board Layout on 3-layer FR4**

*Note: Top layer thickness: 0.2 mm, bottom layer thickness: 0.8 mm, 17 mm Cu metallization, gold plated. Board size: 21 x 21mm.*



**Figure 5 Cross-Section View of Application Board**



**Figure 6** Detail of Application Board Layout

*Note: In order to achieve the same performance as given in this datasheet please follow the suggested PCB-layout as closely as possible. The position of the GND vias is critical for RF performance.*

## 4 Physical Characteristics

### 4.1 Package Footprint

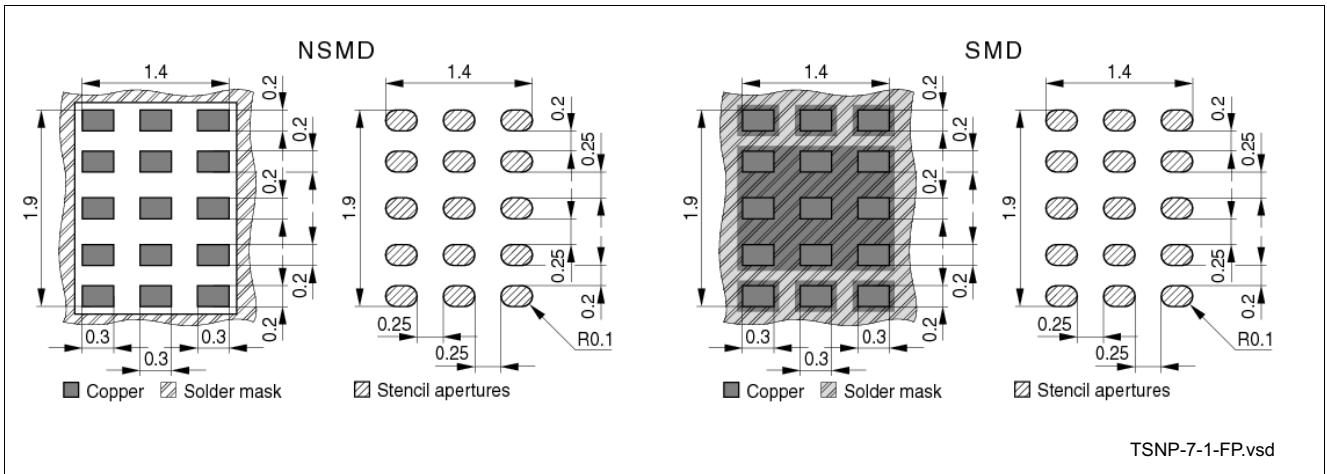


Figure 7 Recommended Footprint and Stencil Layout for the TSNP-7-1 Package

## 4.2 Package Dimensions

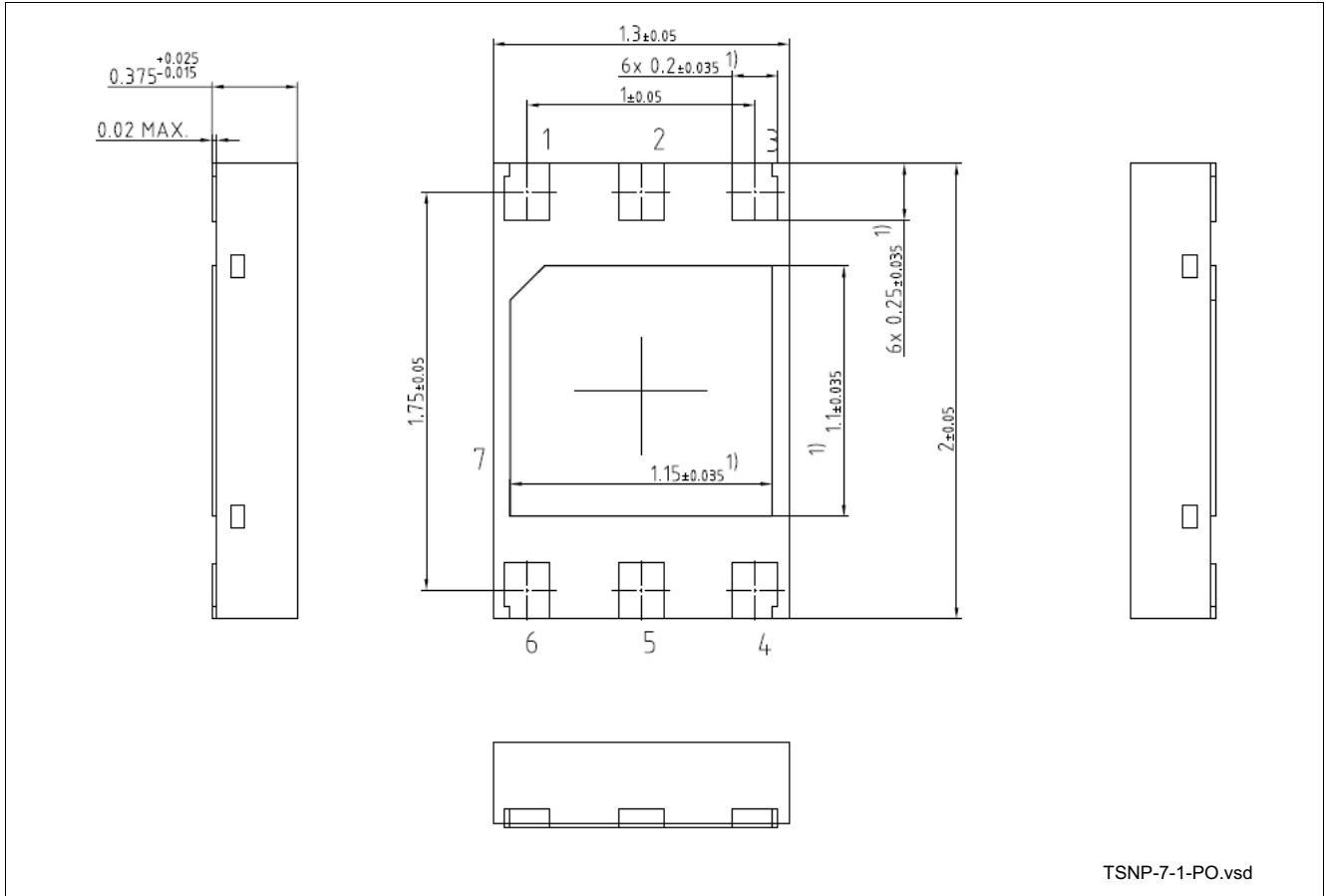


Figure 8 Package Outline (Top, Side and Bottom View)

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